# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com

# HIGH RELIABILITY SILICON POWER RECTIFIER

Qualified per MIL-PRF-19500/246

Glass Passivated Die
Glass to Metal Header Construction
VRRM to 1000V
1600 Amps Surge Rating

DEVICES				LEVELS
1N3289	1N3294	1N3289R	1N3294R	JAN
1N3291	1N3295	1N3291R	1N3295R	JANTX
1N3293		1N3293R		JANTXV

ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = +25°C unless otherwise noted)

Parameters / Test Conditions				Value	Unit
Peak Repetitive Reverse Voltage	1N3289 1N3291 1N3293 1N3294 1N3295	1N3289R 1N3291R 1N3293R 1N3294R 1N3295R	V <sub>RWM</sub>	200 400 600 800 1000	V
Average Forward Current, $T_C = 134^{\circ}$			$I_{\rm F}$	100	А
Peak Surge Forward Current @ $t_p = 8.3$ ms, half sinewave, T <sub>C</sub> = 150°C			I <sub>FSM</sub>	1600	А
Thermal Resistance, Junction to Case			$R_{\theta JC}$	0.4	°C/W
Operating Case Temperature Range			Tj	-65°C to 200°C	°C
Storage Temperature Range			T <sub>STG</sub>	-65°C to 200°C	°C



#### ELECTRICAL CHARACTERISTICS ( $T_A = +25^{\circ}C$ , unless otherwise noted)

Parameters / Test Conditions			Symbol	Min.	Max.	Unit
Forward Voltage $I_{FM} = 310A, T_C = 25^{\circ}C *$			$V_{\text{FM}}$		1.55	V
Reverse Current						
$\begin{split} V_{RM} &= 200, \ T_C = 25^\circ C \\ V_{RM} &= 400, \ T_C = 25^\circ C \\ V_{RM} &= 600, \ T_C = 25^\circ C \\ V_{RM} &= 800, \ T_C = 25^\circ C \\ V_{RM} &= 1000, \ T_C = 25^\circ C \end{split}$	1N3289 1N3291 1N3293 1N3294 1N3295	1N3289R 1N3291R 1N3293R 1N3294R 1N3295R	I <sub>RM</sub>		10	mA
Reverse Current						
$\begin{split} V_{\rm RM} &= 200,  T_{\rm C} = 200^{\circ}{\rm C} \\ V_{\rm RM} &= 400,  T_{\rm C} = 200^{\circ}{\rm C} \\ V_{\rm RM} &= 600,  T_{\rm C} = 200^{\circ}{\rm C} \\ V_{\rm RM} &= 800,  T_{\rm C} = 200^{\circ}{\rm C} \\ V_{\rm RM} &= 1000,  T_{\rm C} = 200^{\circ}{\rm C} \end{split}$	1N3289 1N3291 1N3293 1N3294 1N3295	1N3289R 1N3291R 1N3293R 1N3294R 1N3295R	I <sub>RM</sub>		30	mA

DO-205AA (DO-8)

\* Pulse test: Pulse width 300µsec. Duty cycle 2%

Note:



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### HIGH RELIABILITY SILICON POWER RECTIFIER

#### **GRAPHS**





FIGURE 5 TRANSIENT THERMAL IMPEDANCE



# FIGURE 7 MAXIMUM NONREPETITIVE SURGE CURRENT





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## HIGH RELIABILITY SILICON POWER RECTIFIER

# **PACKAGE DIMENSIONS**



#### NOTES:

- 1. Dimensions are in inches.
- 2. Millimeter equivalents are given for general information only.
- 3. Complete threads to extend to within 2.5 threads of seating plane.
- 4. 375-24 UNF-2A. Maximum pitch diameter of plated threads shall be basic pitch diameter (.3479 inch (8.837 mm) reference.
- 5. A chamfer or undercut on one or both ends of hexagonal portions is optional.
- 6. Minimum flat.
- 7. For marking (see 3.5).
- 8. The body of the device, with the exception of the hexagon and flexible lead extensions, lies within cyclinder defined by  $CD_1$  and CH,  $CD_1$  not to exceed actual HF.
- 9. Terminal shape is optional.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

Symbol	Inches		Millir	Notes	
	Min	Max	Min	Max	
CD	.625	1.000	15.88	25.40	8
$CD_1$		.500		12.70	
СН		1.750		44.45	
CH <sub>1</sub>		1.140		28.96	
с	.050	.120	1.27	3.05	
FL	.300	.450	7.62	11.43	6
FW		.670		17.02	
HF	1.031	1.063	26.19	27.00	
HT	.125	.500	3.18	12.70	5
OAL	4.300	5.065	109.22	128.65	
SD					4
SL	.605	.645	15.37	16.38	
UD	.343	.373	8.71	9.47	
φt	.250	.310	6.35	7.87	4

Physical dimensions